

# CMOS MAPS development for Belle II vertex detector upgrade -- OBELIX sensor for VTX project --

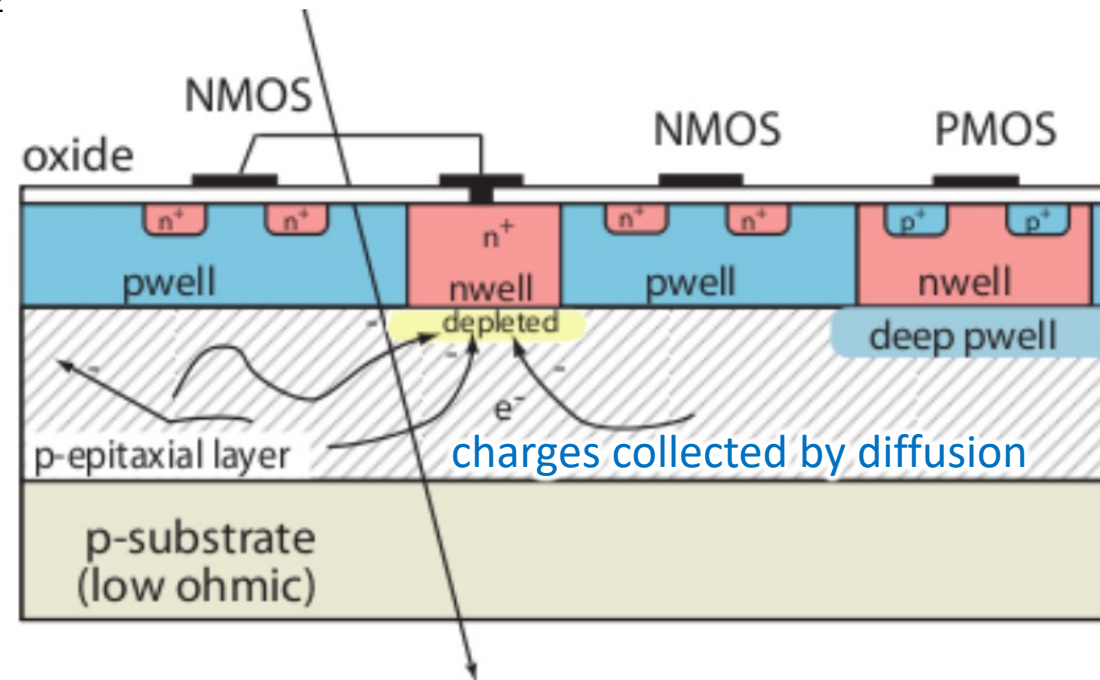
Katsuro Nakamura (KEK)

Mar 29, 2024

研究会「EICで展開する新たな原子核・素粒子物理」

# CMOS Monolithic active pixel sensors (MAPS)

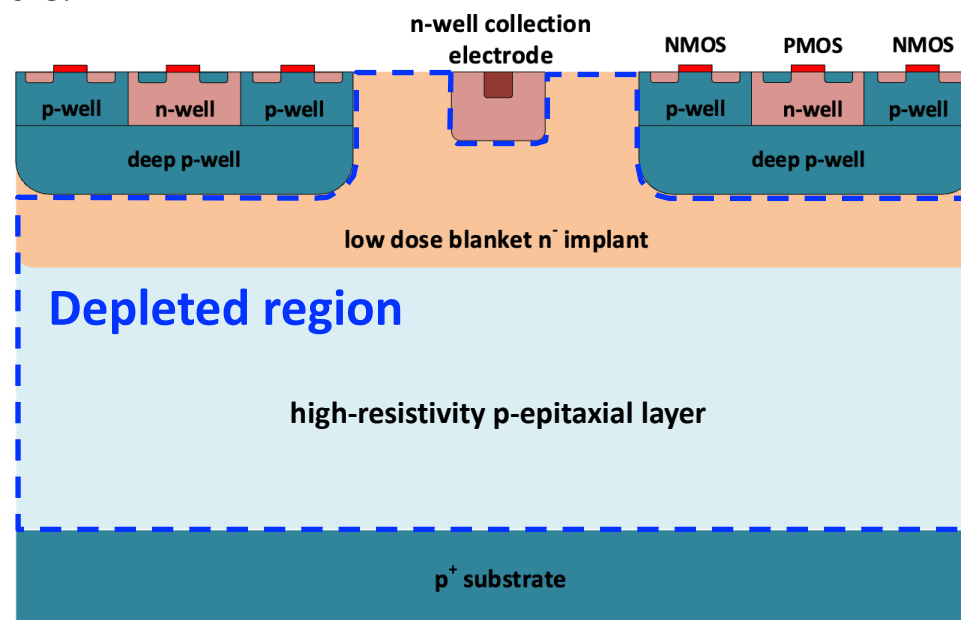
- **Monolithic Active Pixel Sensor (MAPS) based on CMOS imaging processes**
  - Sensor: the epitaxial silicon layer grown on low-cost and low-ohmic substrate wafers
  - Monolithic: full CMOS circuitry integrated into active area and periphery
  - Because in standard CMOS technologies the allowed biasing voltages and epi-material resistivity are low, the depleted region is localized around the electrode.
  - → Charge collection mainly by **diffusion** : slow and incomplete collection was bottleneck.
  - Successfully used in lower hit rate and radiation level than LHC(p-p), like STAR and ALICE.
    - $\text{NIEL} < 10^{13} \text{ n}_{\text{eq}}/\text{cm}^2$



# Depleted Monolithic Active Pixel Sensor (DMAPS)

## ■ Depleted CMOS MAPS

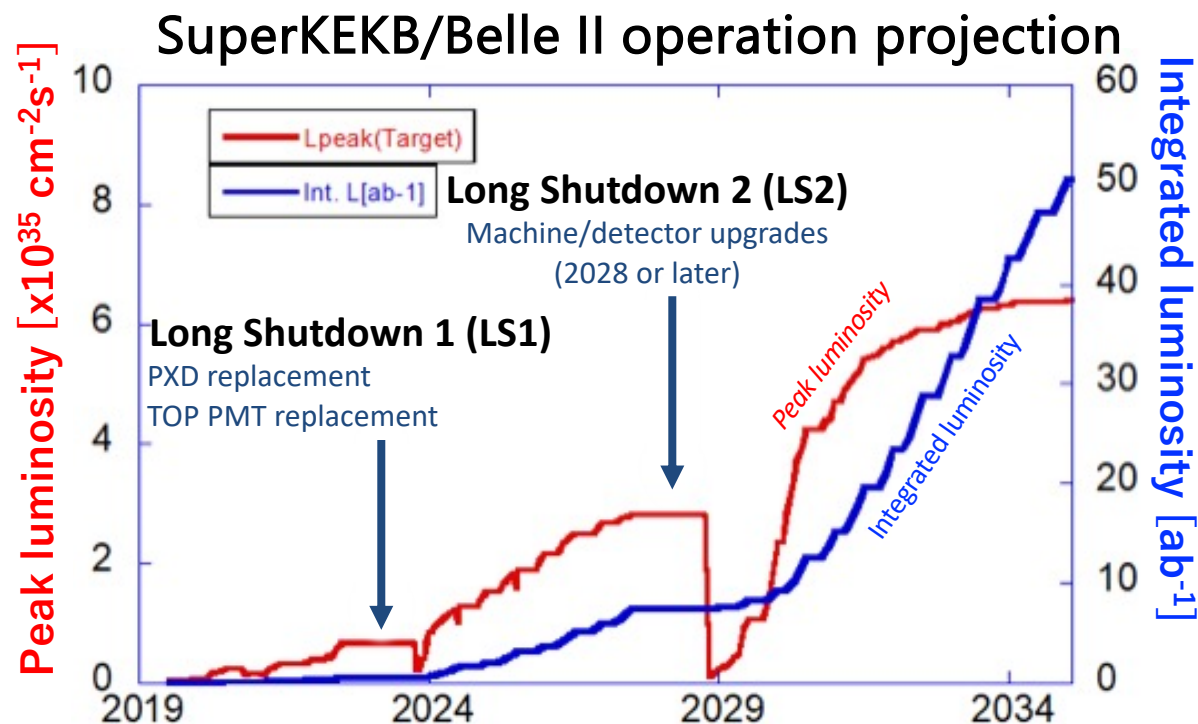
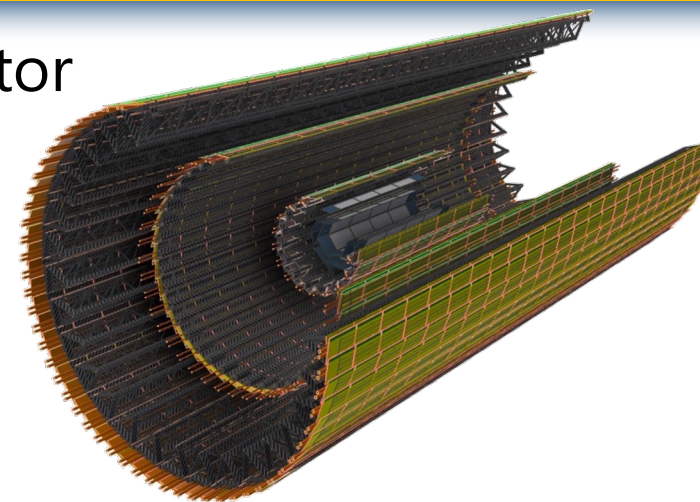
- Improved CMOS technologies utilize high resistivity depleted silicon layers to achieve a depletion region underneath the collection electrode (typically about 20 $\mu$ m)
- Charge collection by **drift** : Fast ( $\sim 10$ ns) and efficient charge collection
- Small collection electrode: Small noise and low power consumption due to small  $C_{\text{det}}$
- Low-dose n layer: full depletion with uniform electric field
- $\rightarrow$  High hit rate and radiation environment tolerance
  - NIEL  $\sim 10^{15}$   $n_{\text{eq}}/\text{cm}^2$  is achievable.



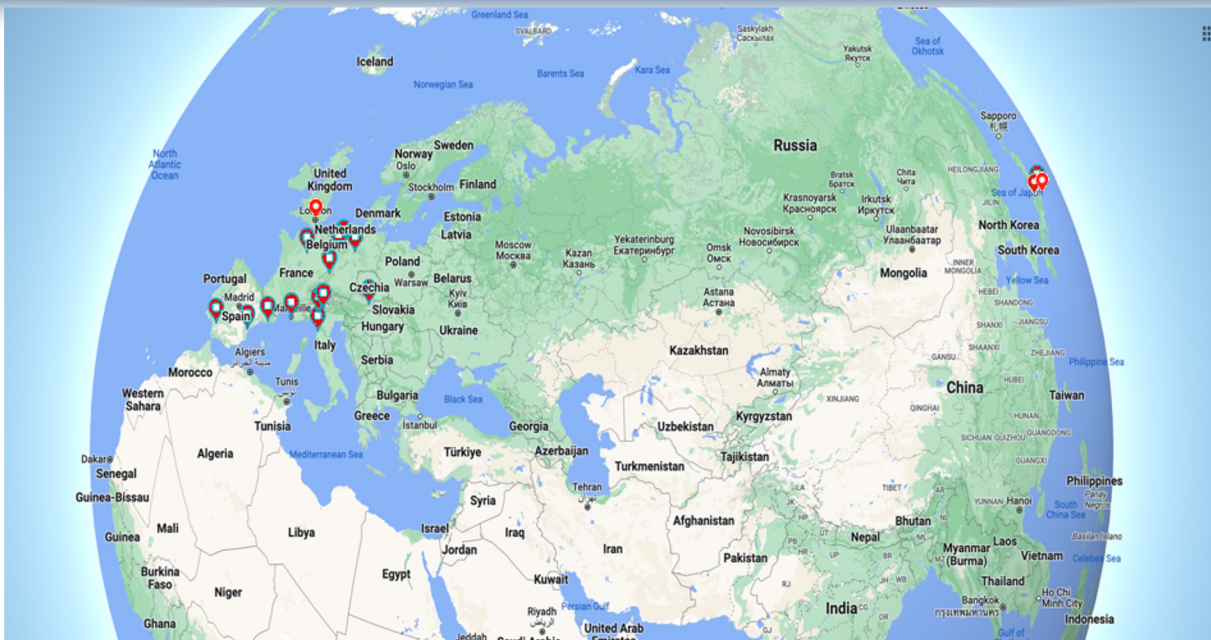
# Belle II Vertex Detector Upgrade

- **New vertex detector VTX:**  
Fully pixelated 5-layer detector, using CMOS MAPS
  - Higher space-time granularity
  - Small material budget: about  $2.4\%X_0$
- **Target installation timescale is LS2 for SuperKEKB machine upgrade.**
  - Still, detailed plans for LS2 are under discussion
- **Thin DMAPS sensor:**  
Optimized BELLE II pIXel (OBELIX) chip
  - New sensor for Belle II vertex upgrade
  - TowerJazz 180nm
- **OBELIX matrix design is based on TJ-Monopix2 for HL-LHC ATLAS**
  - Implementing new digital periphery and trigger logic for Belle II
  - Detailed performance characterization of TJ-Monopix2 is crucial for OBELIX design

VTX detector



# VTX project: DMAPS development for Belle II upgrade



## VTX collaboration

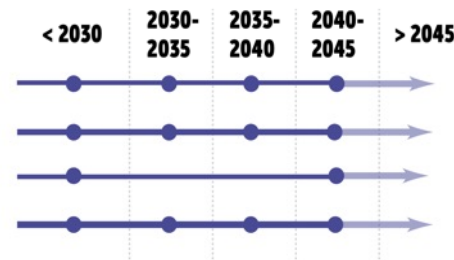
- |                          |                           |
|--------------------------|---------------------------|
| HEPHY (Vienna)           | University of Bergamo     |
| CPPM (Marseille)         | INFN & University of Pisa |
| IJCLab (Orsay)           | INFN Pavia                |
| IPHC (Strasbourg)        | IFAE (Barcelona)          |
| University of Bonn       | IMB-CNM-CSIC (Barcelona)  |
| University of Dortmund   | IFCA (CSIC-UC) Santander  |
| University of Goettingen | IMSE-CNM-CSIC (Seville)   |
| KIT (Karlsruhe)          | IFIC (CSIC-UV) Valencia   |
| KEK (Tsukuba)            | ITAINNOVA (Zaragoza)      |
| University of Tokyo      | QMU (London)              |
| IPMU (Kashiwa)           |                           |

## ■ MAPS in the ECFA Roadmap (DRDT3.1)

– Identified as critical to achieve the science program outlined in European Strategy for Particle Physics

Solid state

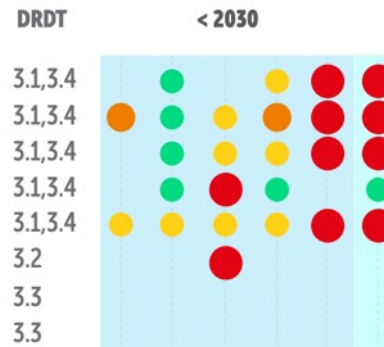
- DRDT 3.1** Achieve full integration of sensing and microelectronics in monolithic CMOS pixel sensors
- DRDT 3.2** Develop solid state sensors with 4D-capabilities for tracking and calorimetry
- DRDT 3.3** Extend capabilities of solid state sensors to operate at extreme fluences
- DRDT 3.4** Develop full 3D-interconnection technologies for solid state devices in particle physics



Panda 2025  
 CBM 2025  
 NA62/Klever 2025  
 Belle II 2026  
 ALICE LS3<sup>1)</sup>  
 AI<sup>1)</sup>

Vertex detector<sup>2)</sup>

Position precision	3.1,3.4
Low X/X <sub>0</sub>	3.1,3.4
Low power	3.1,3.4
High rates	3.1,3.4
Large area wafers <sup>3)</sup>	3.1,3.4
Ultrafast timing <sup>4)</sup>	3.2
Radiation tolerance NIEL	3.3
Radiation tolerance TID	3.3



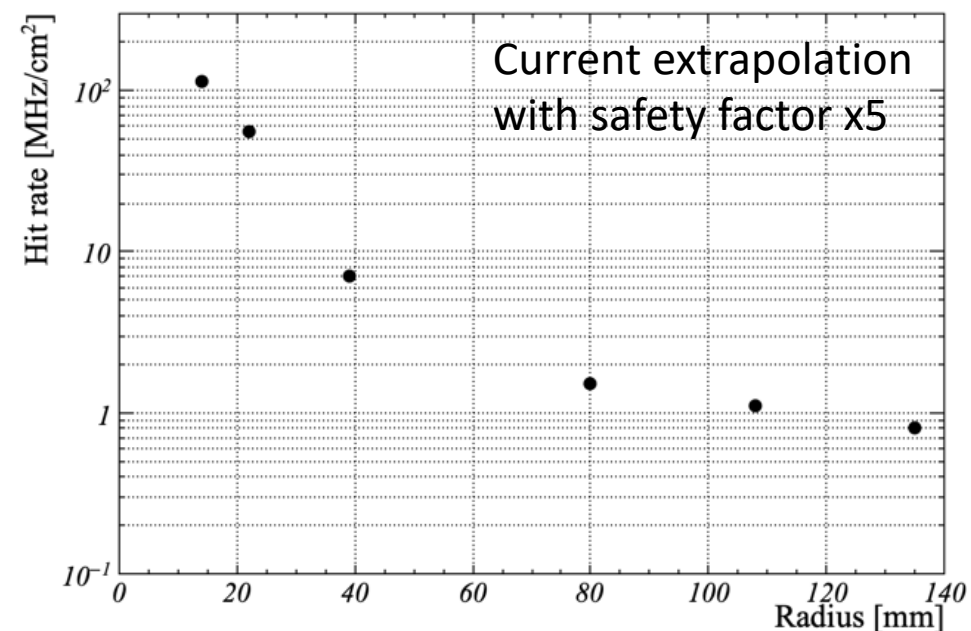
# Requirements for the VXD upgrade

## Targets

Radius range	14 – 135 mm
<b>Tracking &amp; Vertexing performance</b> at least as good as current VXD	
Single point resolution	< 15 $\mu\text{m}$
Material budget per layer	$\sim 0.2\% X_0$ (inner), $\sim 0.8\% X_0$ (outer)
Hit time resolution	< 100 ns
<b>Robustness against radiation environment</b> current extrapolation with safety factor x5	
Hit rate <sup>(*)</sup>	$\sim 120 \text{ MHz/cm}^2$
Total Ionizing Dose <sup>(*)</sup>	$\sim 0.1 \text{ MGy/year}$
NIEL fluence <sup>(*)</sup>	$\sim 5.0 \times 10^{13} \text{ n}_{\text{eq}}/\text{cm}^2/\text{year}$

(\*) requirement for the innermost layer (R=14mm)

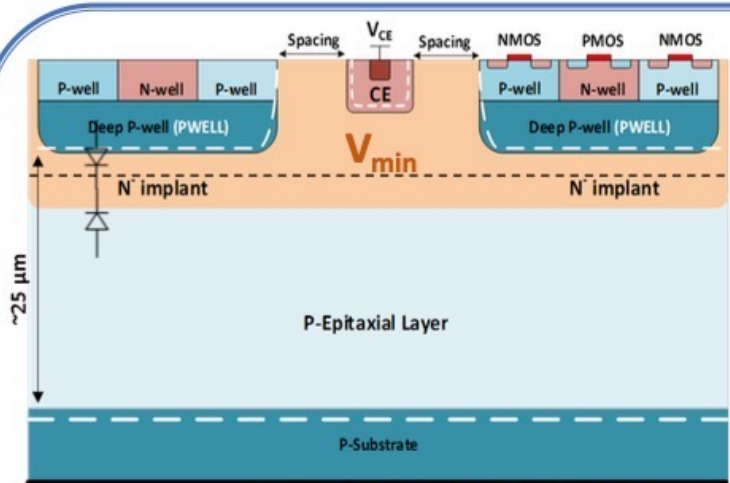
## Required hit rate tolerance vs. Radius



## Possible other improvements by upgrade

- Impact parameter resolution
- Tracking performance for low- $p_T$  tracks
- Longer trigger latency
- Capability of Level-1 trigger creation

# TowerJuzz Monopix-2 (TJ-Monopix2)



W. Snoeys et al. <https://doi.org/10.1016/j.nima.2017.07.046>

$$C_d \leq 3fF$$

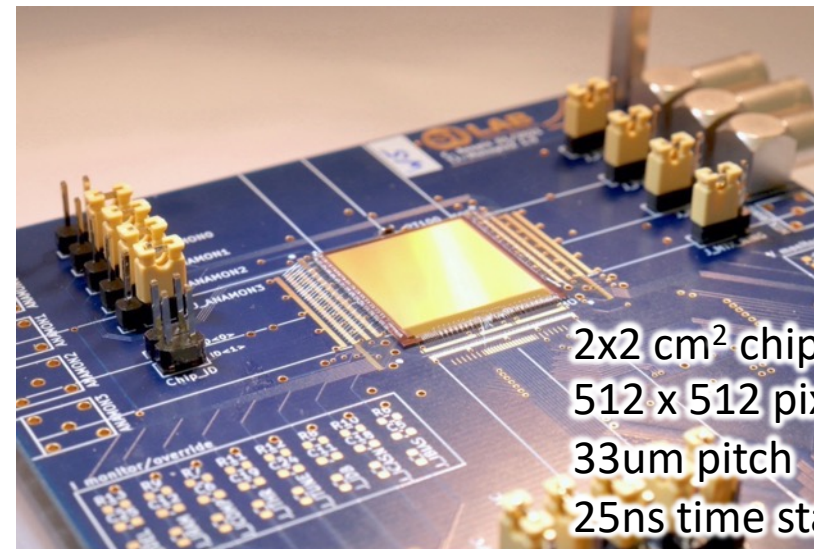
$$P \approx \frac{S}{N} \approx \frac{Q}{C_d}$$

## DMAPS in TJ 180 nm: Concept

- **Small sensor capacitance (Cd)**
  - Key for low power/low noise
- **Radiation tolerance challenges**
  - Modified process
  - Small pixel size
- **Design challenges**
  - Compact, low power FE
  - Compact, efficient R/O

W. Snoeys et al.: [NIM A 871 \(2017\) 90](https://doi.org/10.1016/j.nima.2017.07.046)

## TJ-Monopix2 sensor

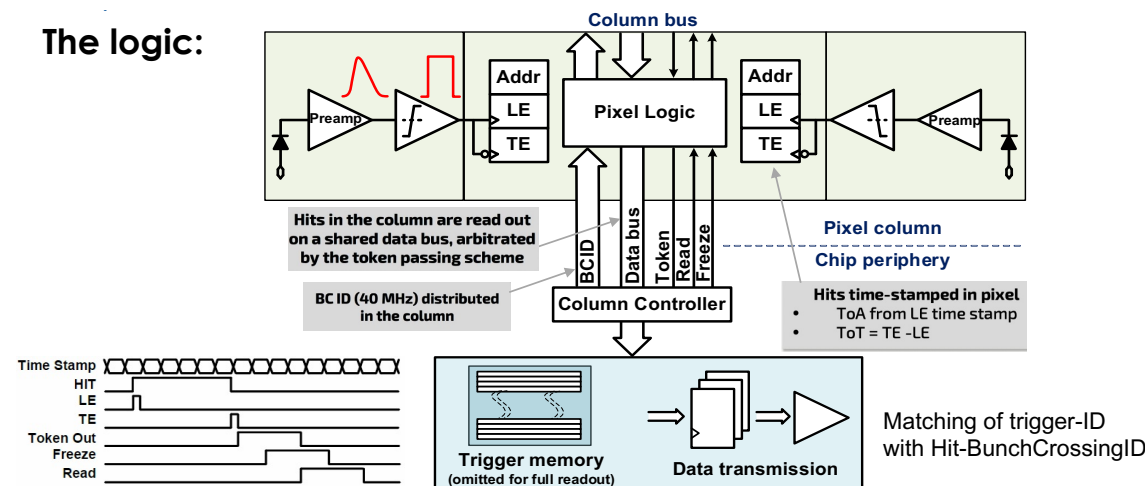


2x2 cm<sup>2</sup> chip  
 512 x 512 pixels  
 33μm pitch  
 25ns time stamping

## TJ-Monopix2 sensor: developed for HL-ATLAS

- DOI: [10.1016/j.nima.2020.164403](https://doi.org/10.1016/j.nima.2020.164403)
- 7-bit ToT, 3-bit in-pixel threshold tuning
- Column-drain read-out inherited from ATLAS FE-I3
- Detection efficiency assessed up to 10<sup>15</sup> neq/cm<sup>2</sup>

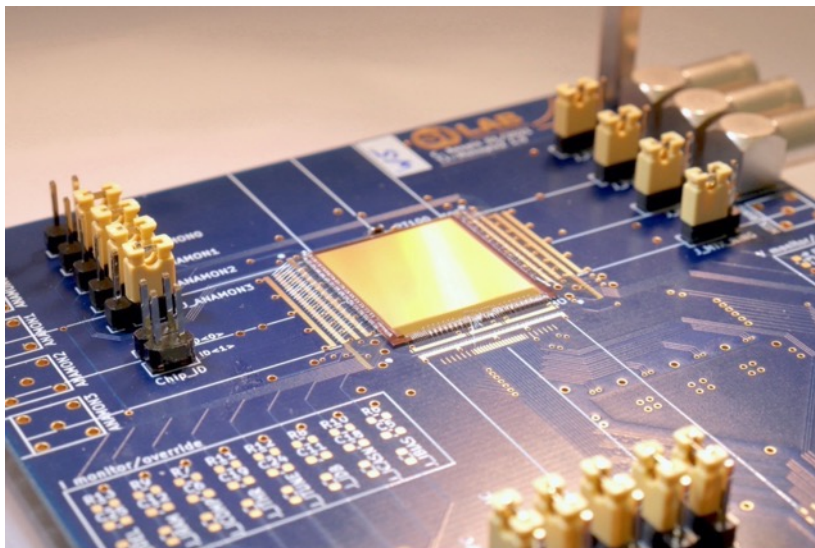
### The logic:



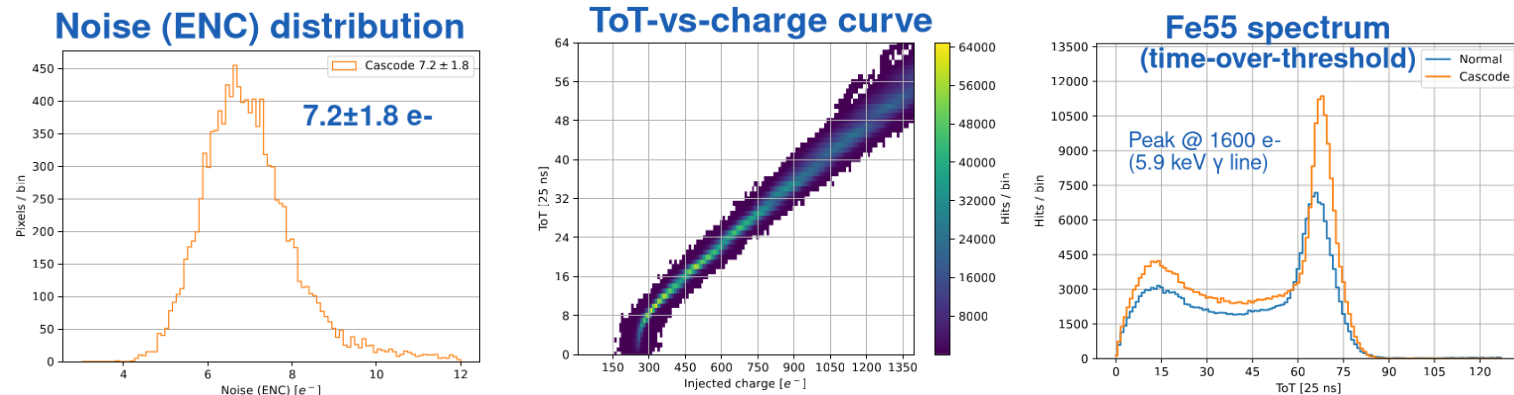
K. Moustakas: CERN-THESIS-2021-146

# TJ-Monopix2 Performance Characterization

## TJ-Monopix2 sensor

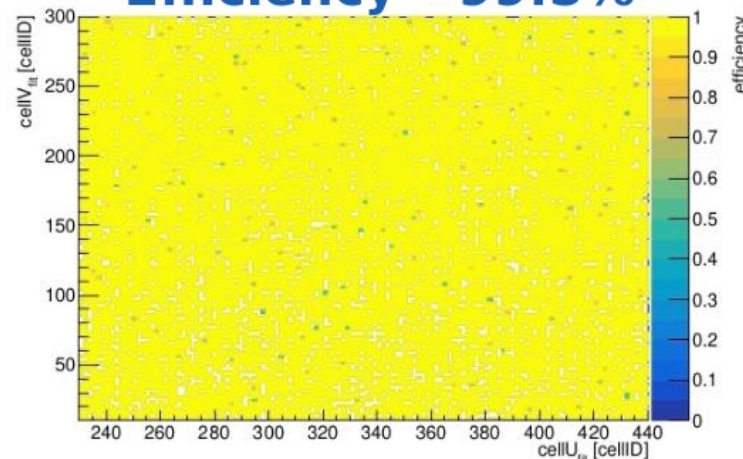


## Lab-testbench measurement

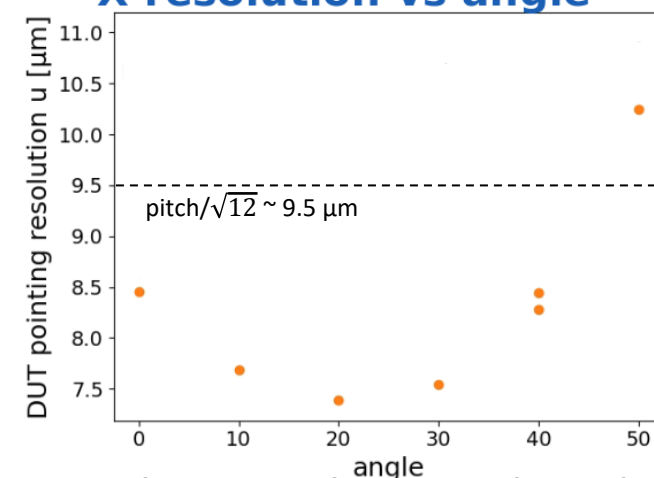


## DESY electron beam measurements

### Efficiency ~99.5%



### X resolution vs angle



## Detailed performance characterization of TJ-Monopix2

- Laboratory testbench test
- Several beam tests

## Including irradiated samples

- High efficiency even w/  $5 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$

- Cross-talk from FREEZE signal prevents to achieve threshold close to electrical noise level
- Bonding issues while preparing new test modules:  $\rightarrow$  Currently,  $\sim 30\%$  success rate



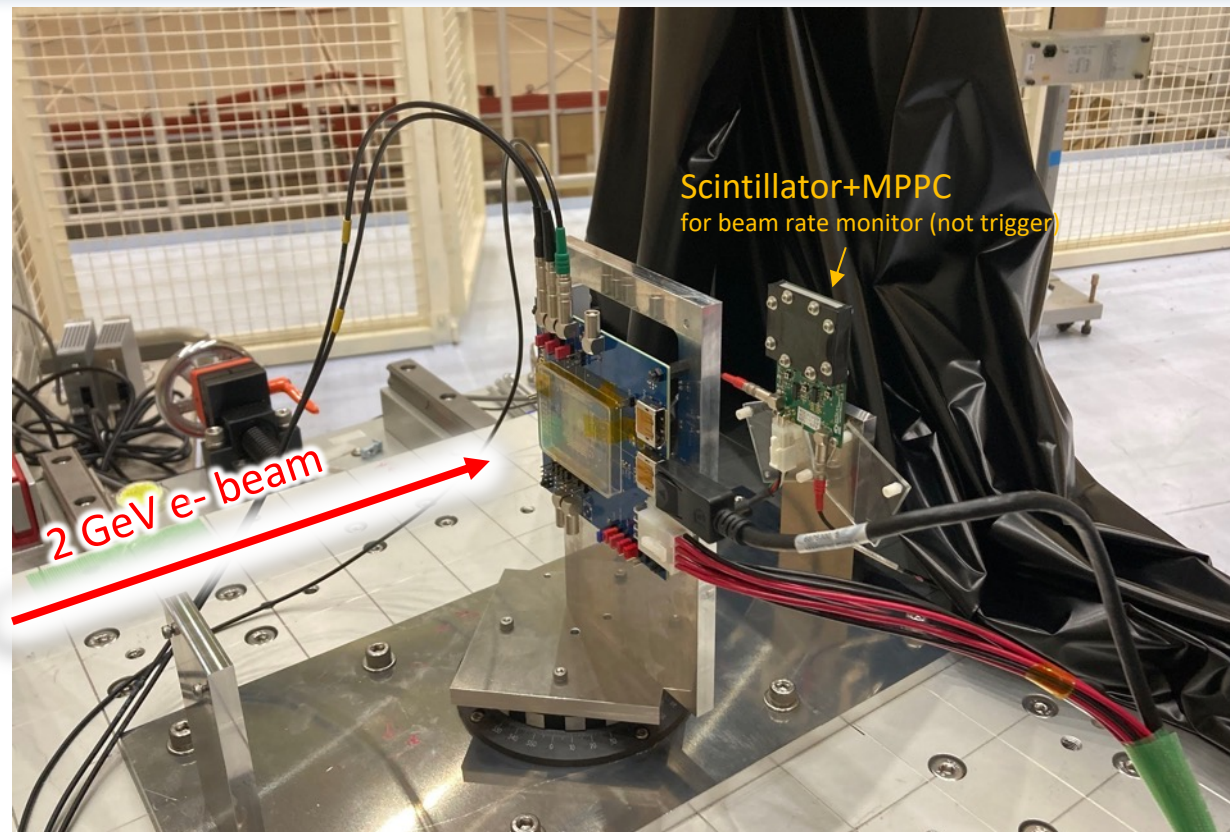
# TJ-Monopix2 test setup in KEK



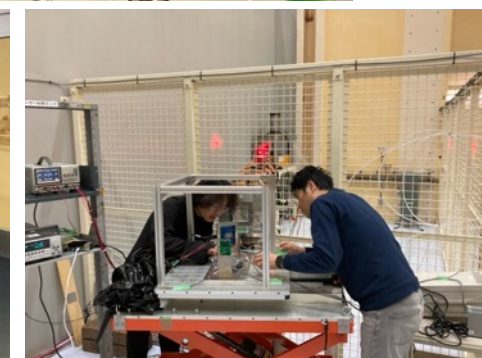
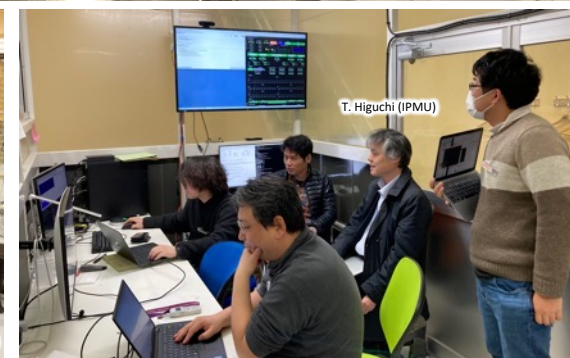
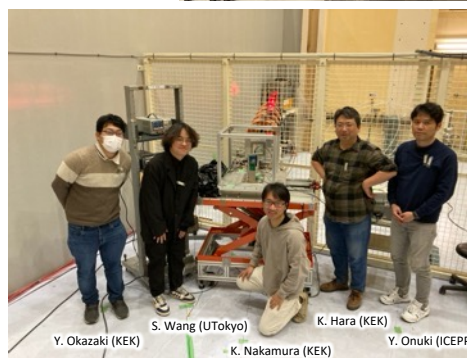
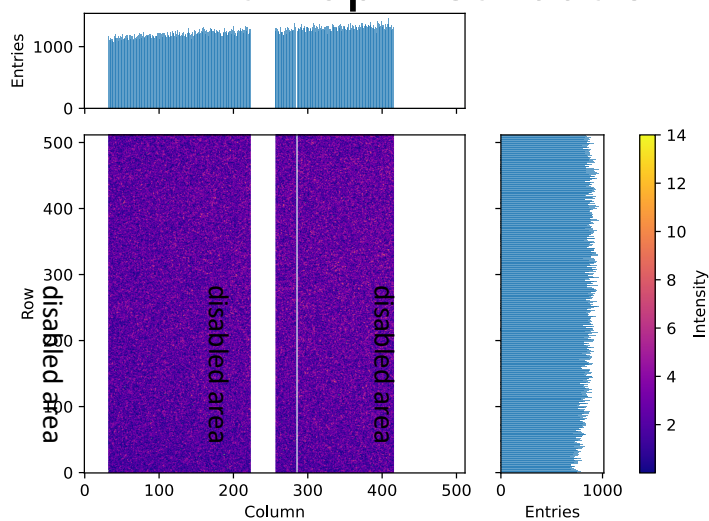
- **Test bench in KEK Fuji Hall B1 floor.**
  - Supported by KEK ITDC
- **In Japan, KEK, UTokyo, ICEPP, IPMU contribute to characterisation of the TJ-Monopix2 chip.**

# Test in KEK PF-AR electron testbeam line

- **KEK PF-AR e- beam (2-5 GeV)**
  - New MAPS performance test hub in Japan
- **Tested a TJ-Monopix2 chip in the beamline on Mar 2024 as a start-up**
  - cluster size measurement with different incident angles
    - → evaluate depletion layer depth

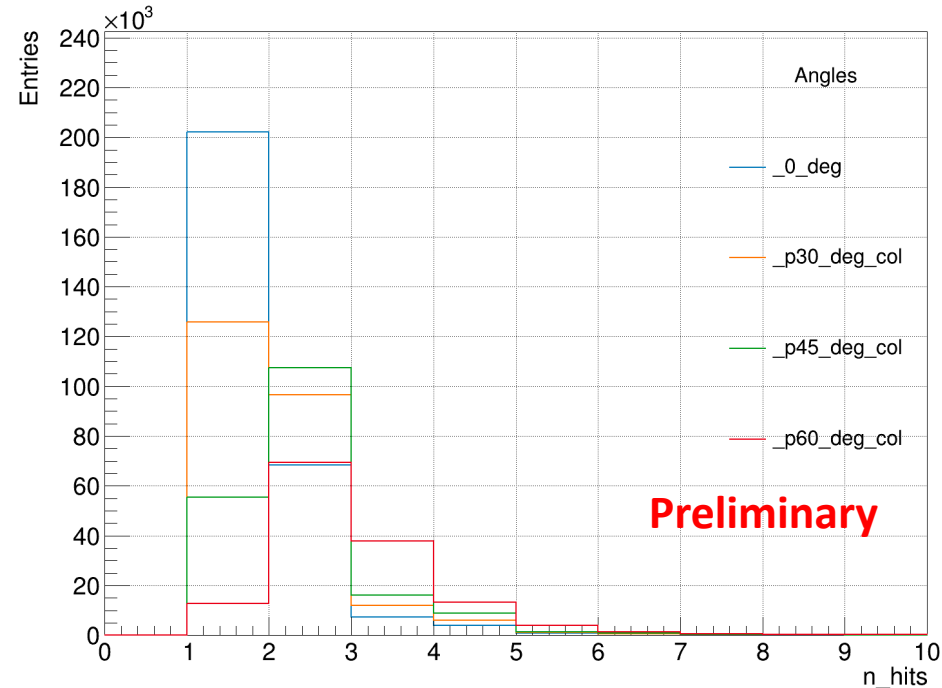


## Hit Map Distribution

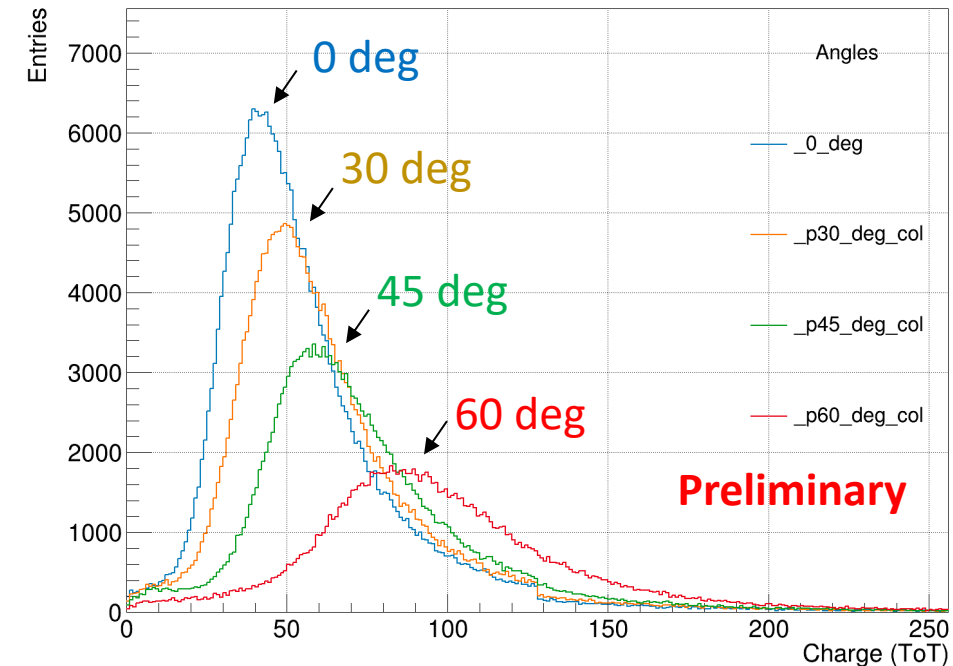


# Preliminary test results

## Cluster size (# of pixels)



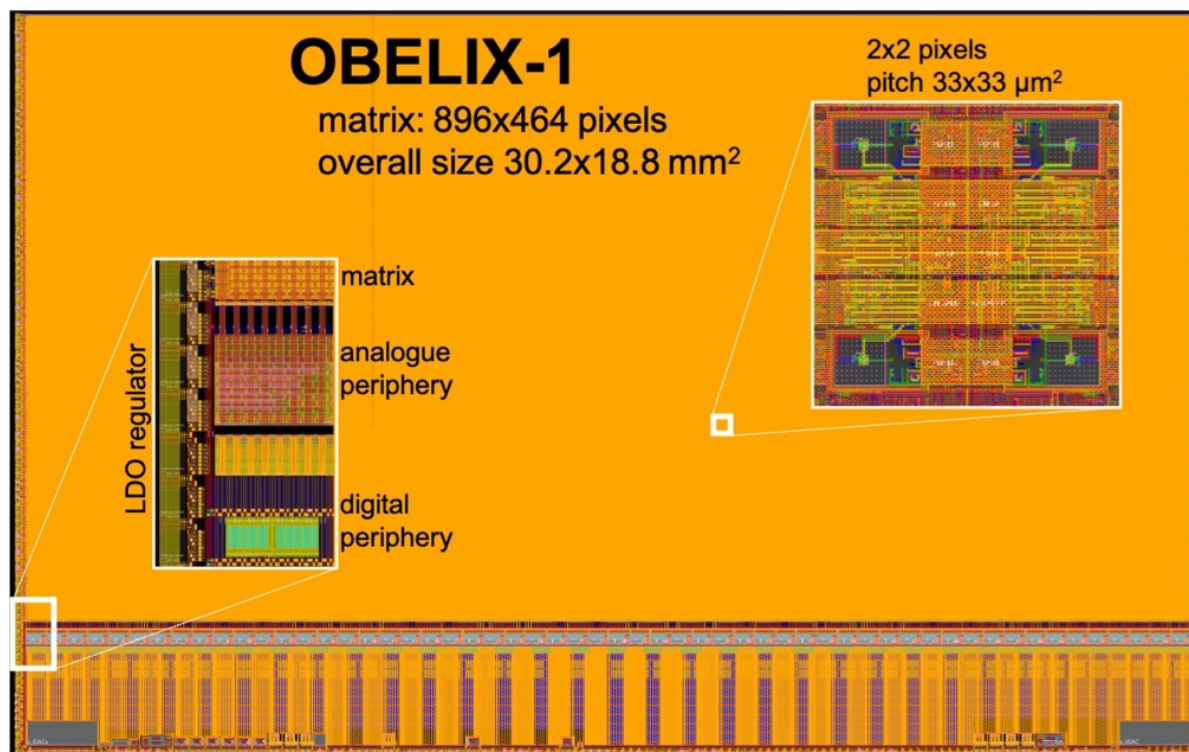
## Cluster charge (sum of ToT)



- Reasonable cluster size and charge distributions under various incident angles
- Analysis of depletion zone depth is ongoing

# OBELIX prototype production

## OBELIX prototype sensor (OBELIX1)



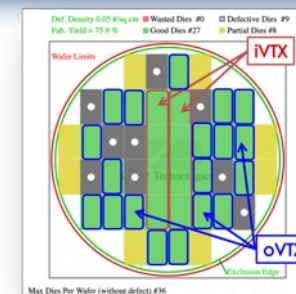
- **1st OBELIX prototype sensor: OBELIX1**
  - All necessary functions for operation will be integrated.
  - Finalizing the design now.
- **OBELIX1 design ongoing: submission in late 2024**

	TJ-Monopix2	OBELIX (target)
Year	2020	2024 (1st prototype)
Pixel pitch	33 μm	33 μm
Sens. area	17x17 mm <sup>2</sup>	~30x16 mm <sup>2</sup>
Sens. thickness	25-100 μm	~30 μm
ToT	7-bit	7-bit
Integration	25 ns	25 to 100 ns
Bandwidth	320 MHz	320 MHz
Power	200 mW/cm <sup>2</sup>	< 200 mW/cm <sup>2</sup>
TID fluence	0.1 MGy 10 <sup>15</sup> n <sub>eq</sub> /cm <sup>2</sup>	< 1 MGy < 5x10 <sup>14</sup> n <sub>eq</sub> /cm <sup>2</sup>

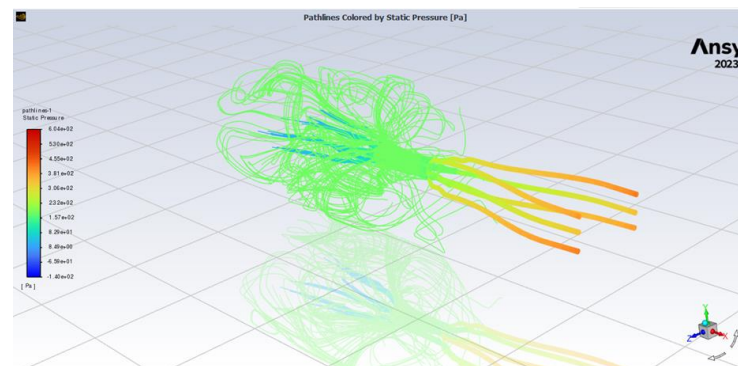
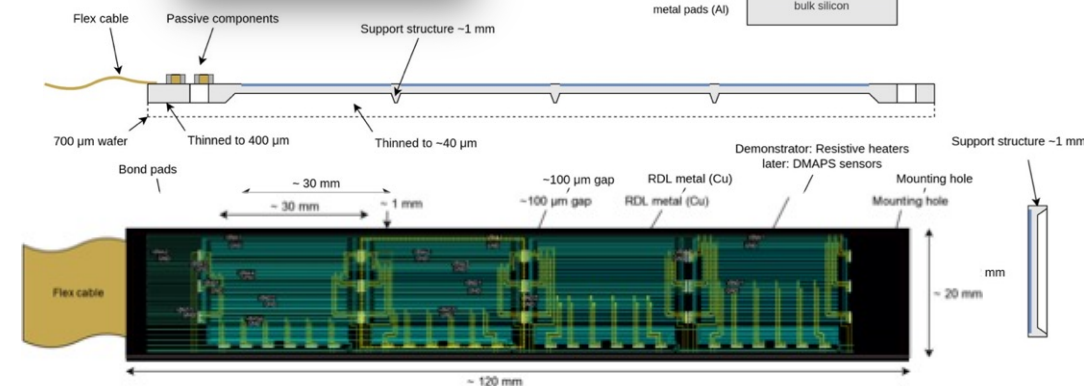
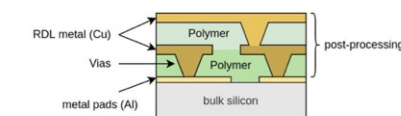
# iVTX Inner Layer Concept

- All-silicon module  $< 0.15 \% X_0$ 
  - 4 contiguous sensors diced as a block from the wafer
  - Redistribution layer for interconnection
  - Heterogeneous thinning for thinness & stiffness
- Prototyping
  - First real-size ladders at IZM-Berlin with dummy Si
    - True iVTX geometry available

- Simulation on cooling
  - Dry air cooling  $15^\circ\text{C}$
  - Assume  $200 \text{ mW/cm}^2$



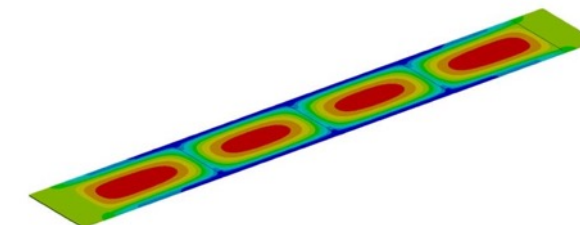
## Cu Redistribution layer (RDL)



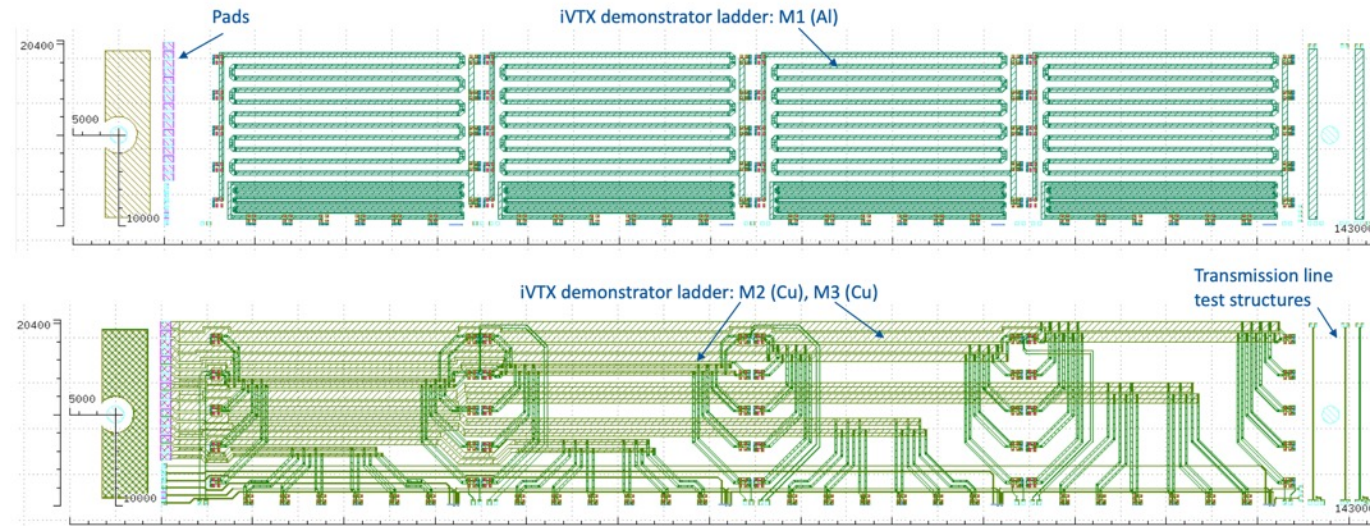
B: Coques  
 Temperature  
 Type: Temperature  
 Unit: °C  
 Temps: 1 s  
 03/06/2022 10:57

19,838 Max  
 19,723  
 19,609  
 19,494  
 19,38  
 19,265  
 19,151  
 19,036  
 18,922  
 18,807 Min

$T_{\text{MAX}} \sim 20^\circ\text{C}$   
 $\Delta T < 5^\circ\text{C}$



# Demonstrator mockup with dummy Si

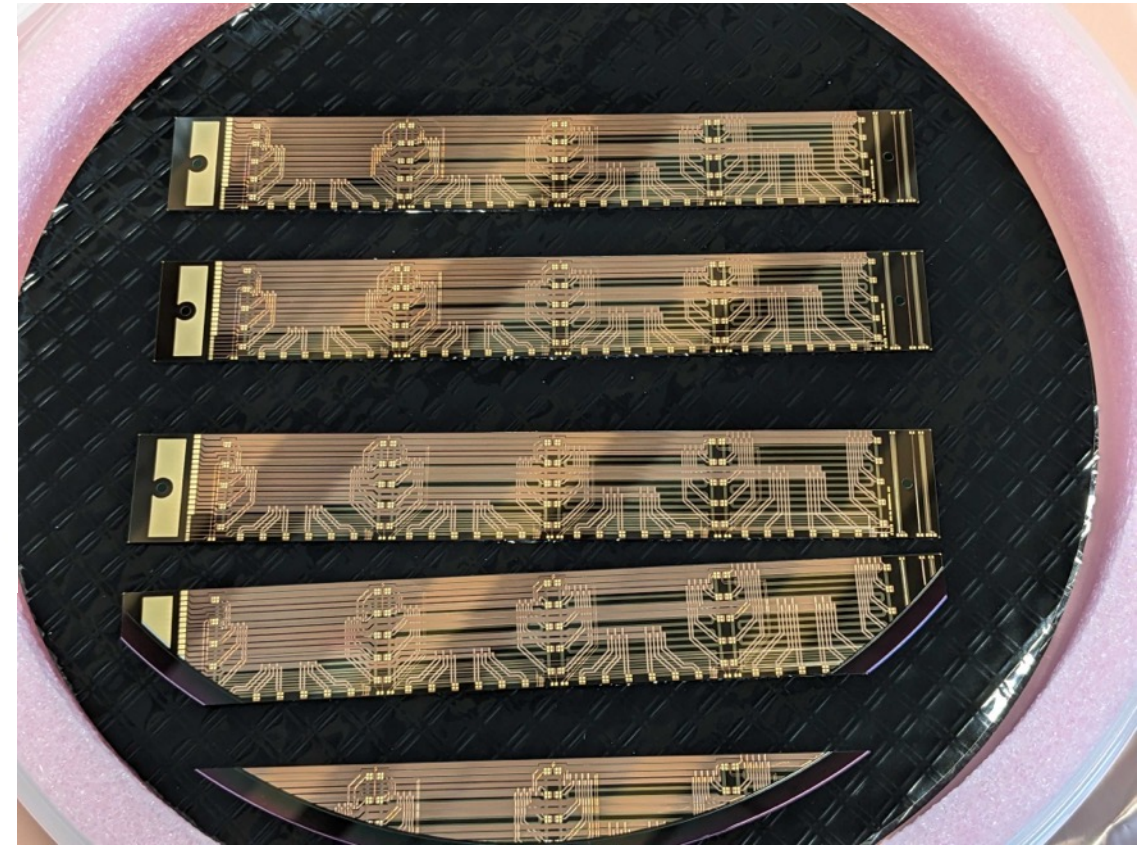


## Metal system:

- Resistive heaters: 1.5  $\mu\text{m}$  Al (M1)
- 2 RDL metal layers: 3  $\mu\text{m}$  Cu (M2, M3)
- Top metal finish: NiAu (M4)

Wirebonding, SMD soldering

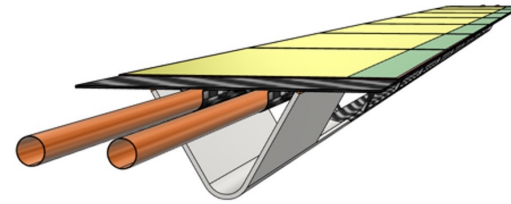
Final ladder dimension: 143 x 20.4  $\text{mm}^2$



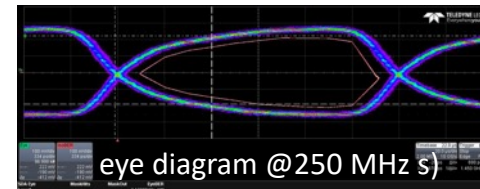
Production finished smoothly  
Characterization starting

# oVTX Outer Layer Concept

- Long ladders
  - Evolving from ALICE-ITS2
    - Carbon-fiber truss support frame
    - Cold-plate with water coolant
    - Long-flex for power & data
- Prototypes for L5 under test
  - Deformation & vibration
    - Max sagitta  $\sim 500 \mu\text{m}$
    - First resonance  $f=250 \text{ Hz}$
  - Signal propagation
  - Cooling at  $T_{\text{room}} \sim 24^\circ\text{C}$ 
    - Leakless water flow at  $T_{\text{in}} = 10^\circ\text{C}$
    - Heaters dissipating  $200 \text{ mW/cm}^2$
    - $22^\circ\text{C} < T_{\text{sensors}} < 26^\circ\text{C}$



- L3-4, radius 4-9 cm, length  $< 50 \text{ cm}$ 
  - Single sensor row,  $\sim 0.5 \% X_0$
- L5, radius 14 cm, length 70 cm
  - Double sensor rows,  $\sim 0.8 \% X_0$



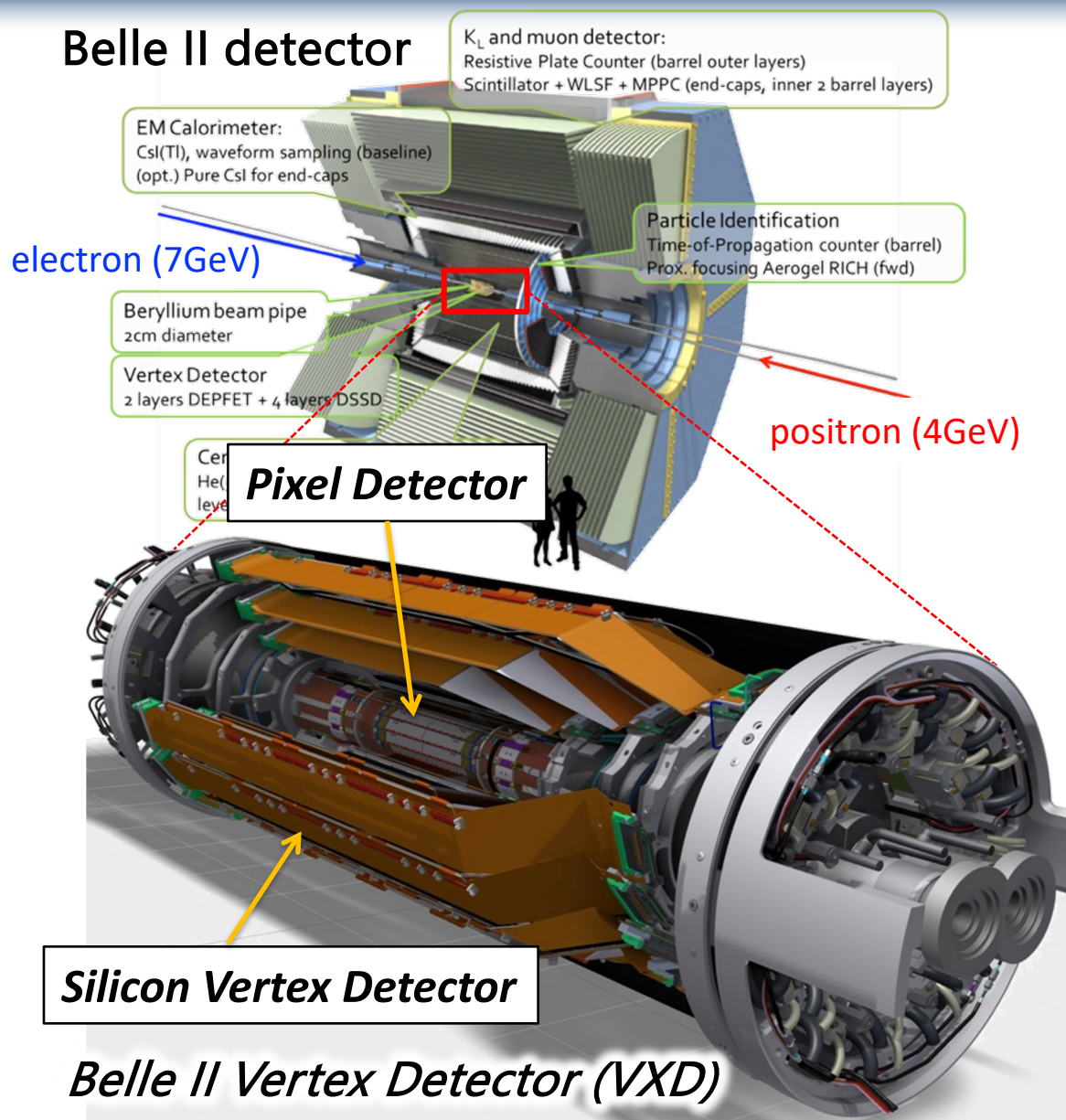
# Summary

- **CMOS DMAPS for Belle II vertex detector upgrade**
  - OBELIX sensor: based on TJ-Monopix2 matrix design
- **Detailed performance characterization of TJ-Monopix2 is being performed for tuning OBELIX design.**
  - Excellent performance is confirmed.
  - KEK and other Japanese institutes are participating in the performance test, using the KEK PF-AR electron beam facility.
- **The first prototype OBELIX1 plan to be submitted in late 2024.**
- **Mechanics design work for the VTX detector is ongoing.**



backup

# Current Vertex Detector at Belle II Experiment



## ■ VXD: Current Vertex detector in Belle II

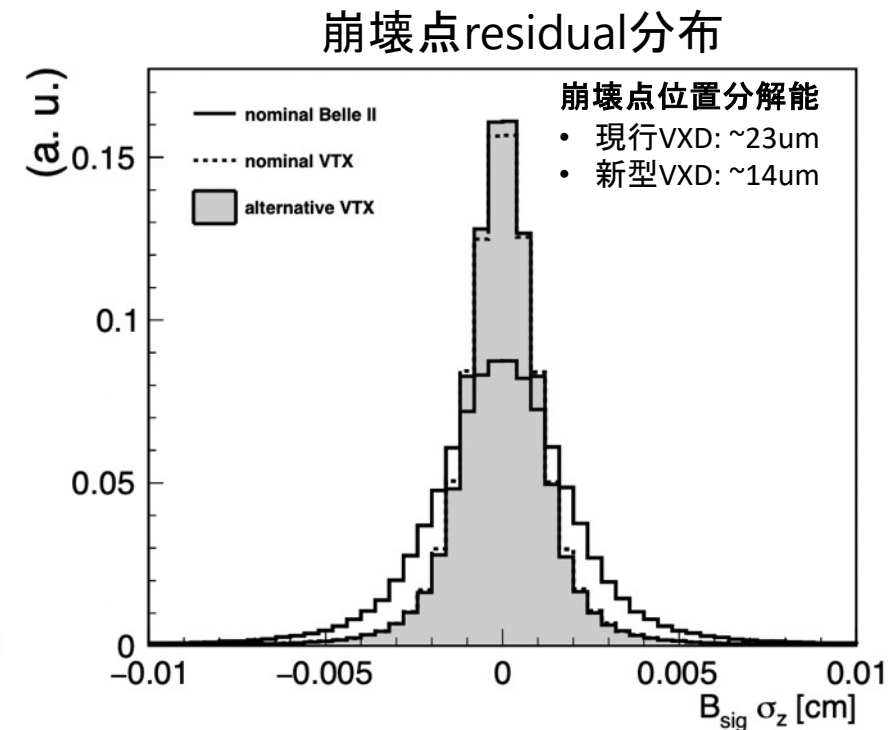
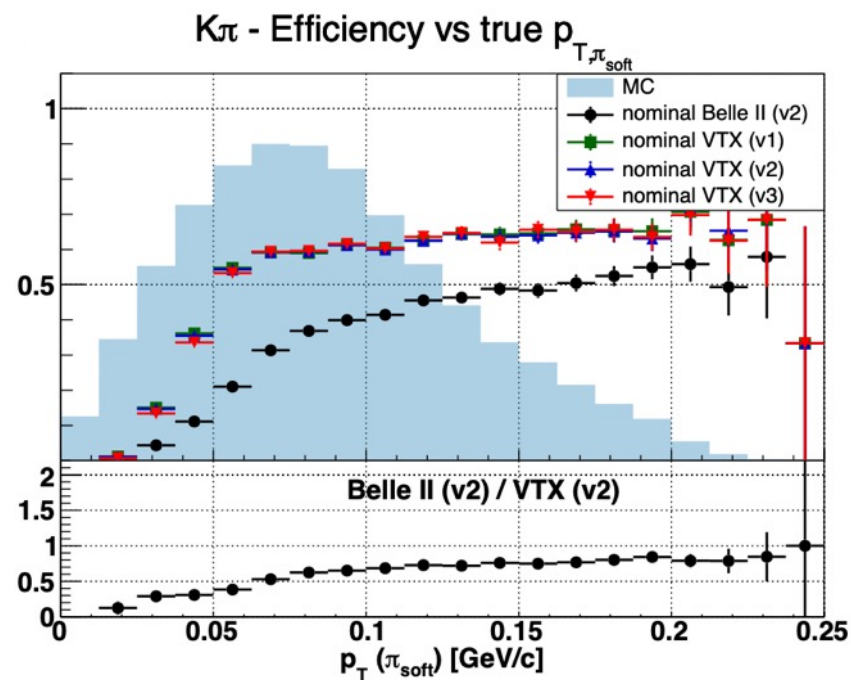
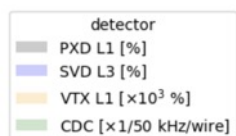
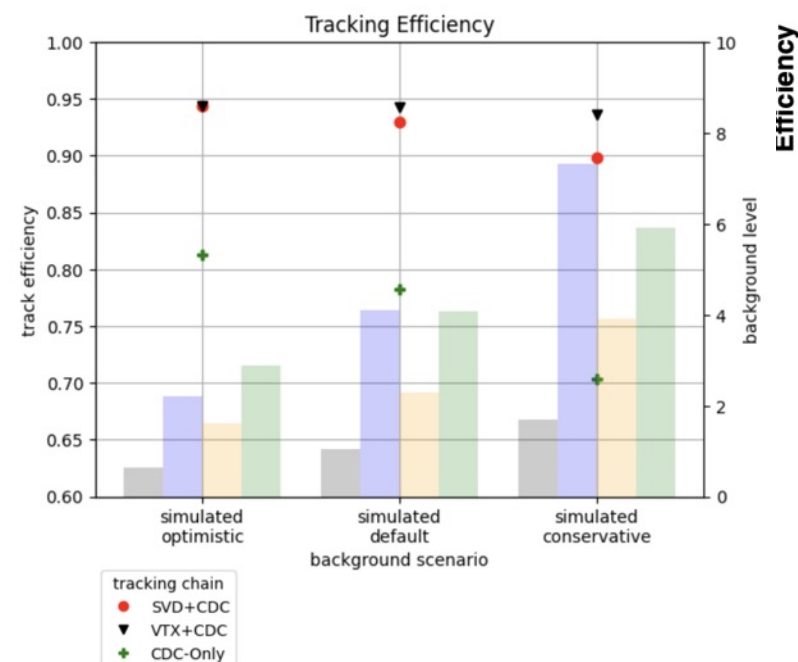
- 2 layers of PiXel Detector (PXD): DEPFET sensor
- 4 layers of Silicon Vertex Detector (SVD):  
Double-sided silicon strip (DSSD) sensor

*SVD technical paper: [arXiv:2201.09824](https://arxiv.org/abs/2201.09824)*

## ■ Roles of VXD

- Determine the vertex position
- Standalone tracking
- PID using SVD  $dE/dx$  for low  $p_T$  tracks

# Performance improvement by VTX

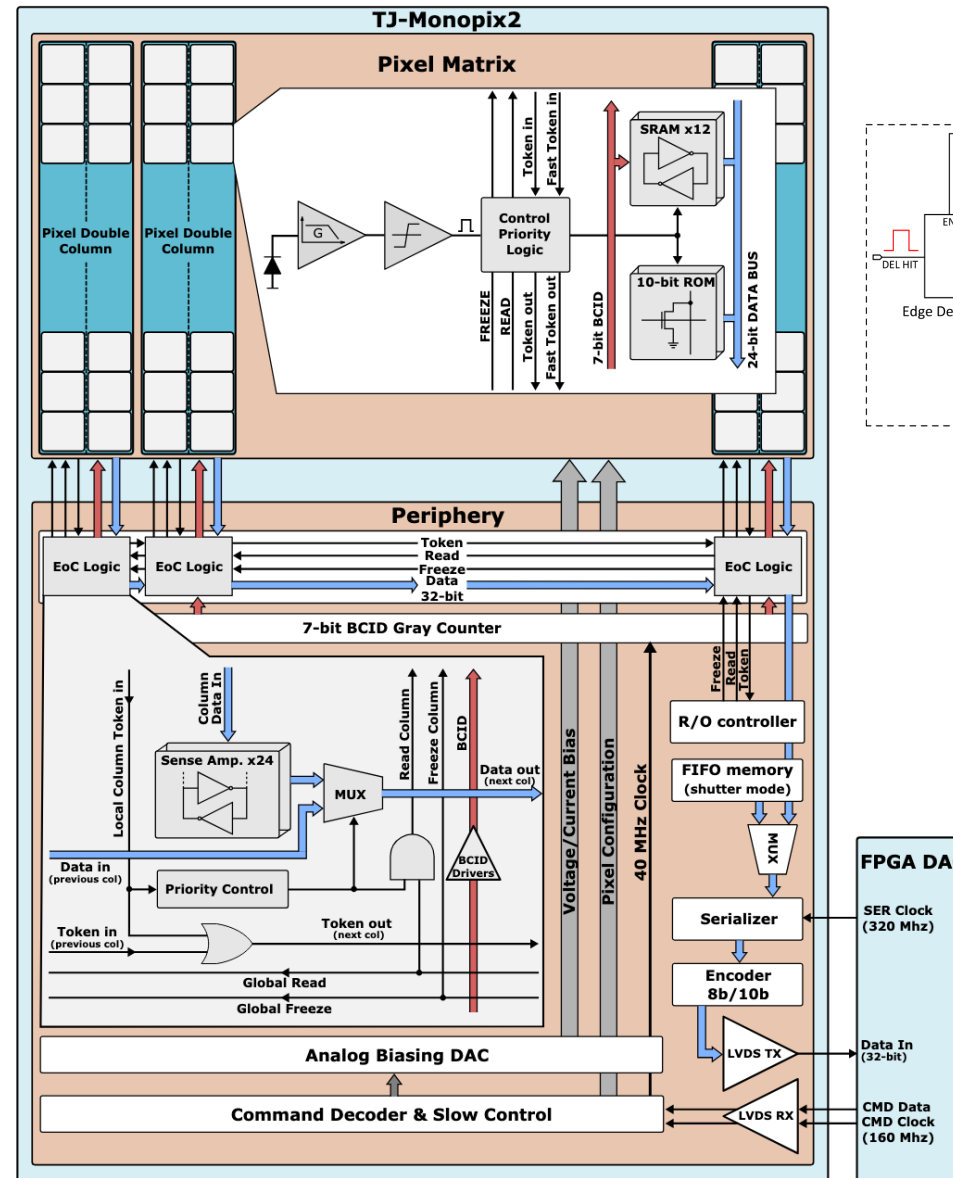


- Recovery in the tracking efficiency at future background level
- Soft pion efficiency: Factor 1.5-4.0 improvement below 75MeV/c
- B vertex resolution:  $\sim 40\%$  better resolution

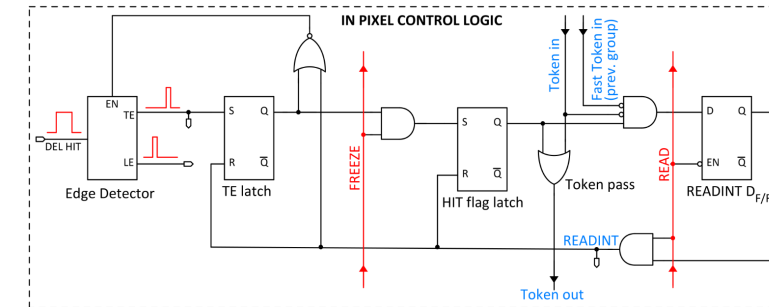
# Column-Drain Readout Scheme

## Token-pass logic to read out 24-bit ToT+ToA data only from hit pixels

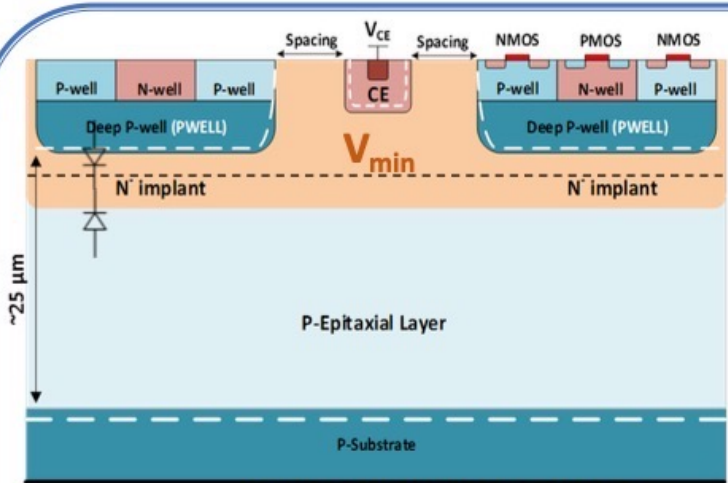
- Hit pixels generate tokens.
- When R/O controller finds the token, it starts reading out 24-bit data, selecting each hit pixel one-by-one using FREAZE/READ signals.



## Control Priority Logic



# OBELIX (Optimized BELle II monolithic pIXel sensor)



W. Snoeys et al. <https://doi.org/10.1016/j.nima.2017.07.046>

$$C_d \leq 3fF$$

$$P \approx \frac{S}{N} \approx \frac{Q}{C_d}$$

## DMAPS in TJ 180 nm: Concept

- **Small sensor capacitance ( $C_d$ )**
  - Key for low power/low noise
- **Radiation tolerance challenges**
  - Modified process
  - Small pixel size
- **Design challenges**
  - Compact, low power FE
  - Compact, efficient R/O

W. Snoeys et al.: [NIM A 871 \(2017\) 90](#)

## OBELIX sensor for Belle II VXD upgrade (VTX)

– Extension from TJ-Monopix2, adapting digital part for Belle II requirement

– TowerJazz 180nm

## 1st prototype design ongoing

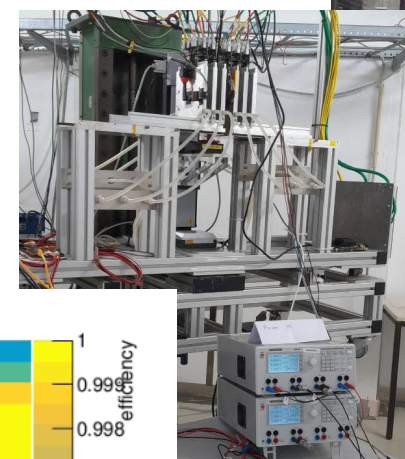
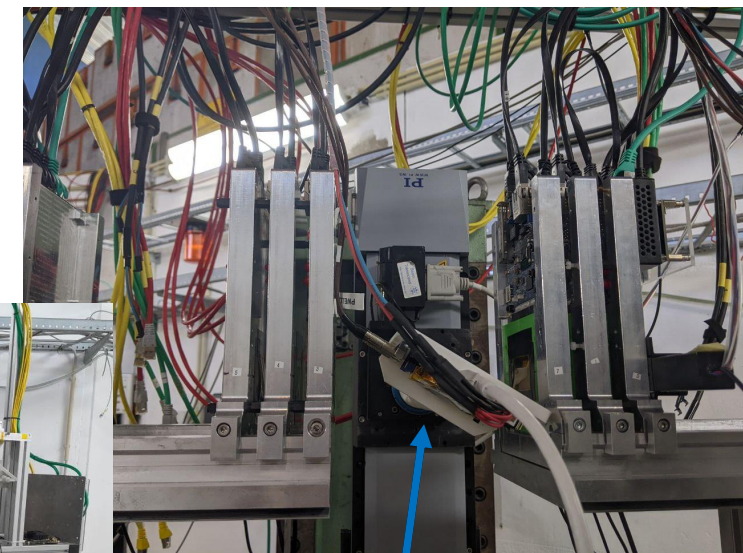
	TJ-Monopix2	OBELIX (target)
Year	2020	2024 (1st prototype)
Pixel pitch	33 $\mu\text{m}$	33 $\mu\text{m}$
Sens. area	17x17 $\text{mm}^2$	$\sim 30 \times 16 \text{ mm}^2$
Sens. thickness	25-100 $\mu\text{m}$	$\sim 30 \mu\text{m}$
Integration	25 ns	25 to 100 ns
Bandwidth	320 MHz	320 MHz
Power	200 $\text{mW}/\text{cm}^2$	$< 200 \text{ mW}/\text{cm}^2$
TID fluence	0.1 MGy $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$	$< 1 \text{ MGy}$ $< 5 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$

# Irradiated TJ-Monopix2 Beam Test

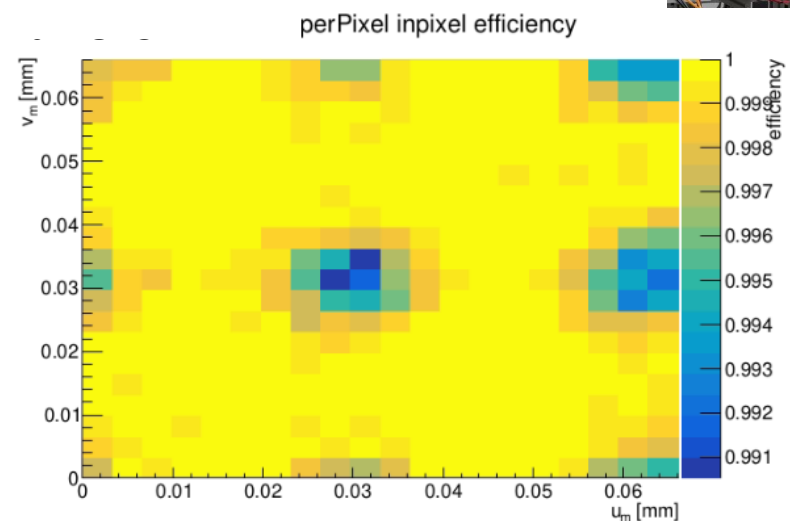
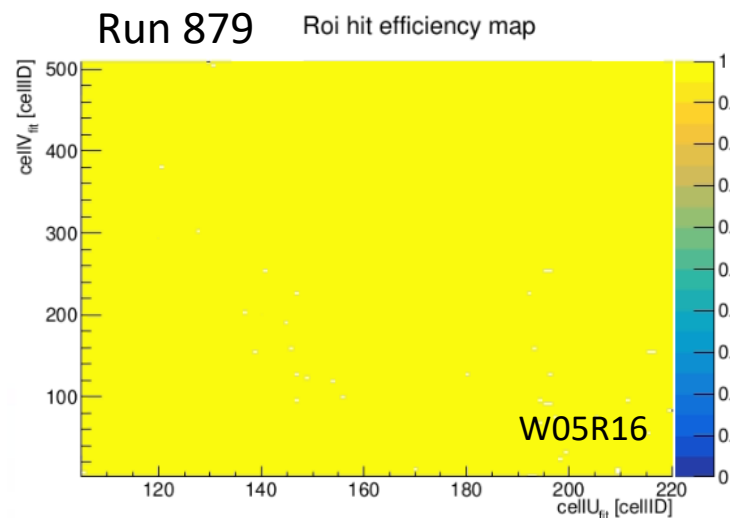
Serial	Irradiation	Substrate
W02R05	None	30 $\mu\text{m}$ EPI
W02R09	Neutrons $1 \times 10^{14}$	30 $\mu\text{m}$ EPI
W05R16	Protons $5 \times 10^{14}$	30 $\mu\text{m}$ EPI
W08R19	None	30 $\mu\text{m}$ EPI
W14R12	None	Cz

Parameter scans:  
HV, IBias, PSub, VClip, BCID, ...

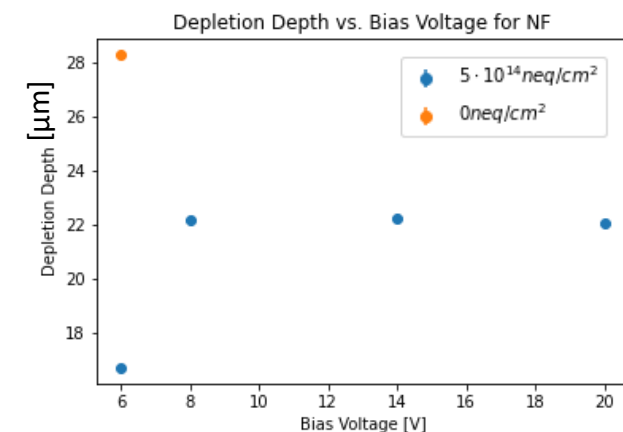
Angular scans, resolution, efficiency



Efficiency  $>99\%$  for  $5 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$  (310  $e^-$  threshold)  
Cluster position residuals  $\sim 9.5 \mu\text{m}$



Telescope planes 4-6  
TJ-Monopix2  
Telescope planes 1-3



cmarinas@ific.uv.es

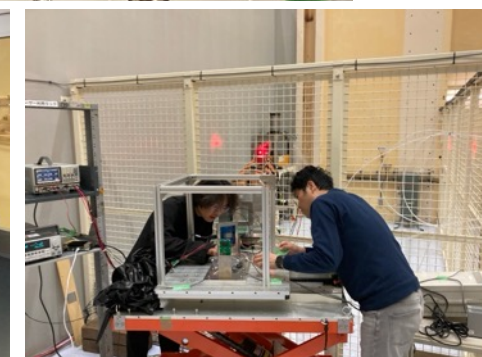
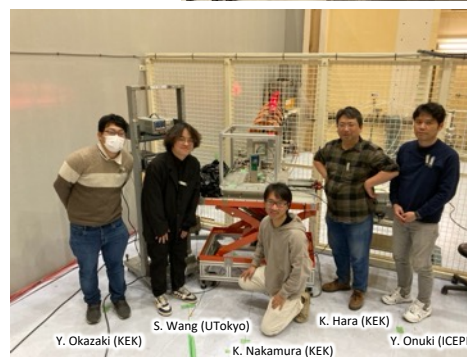
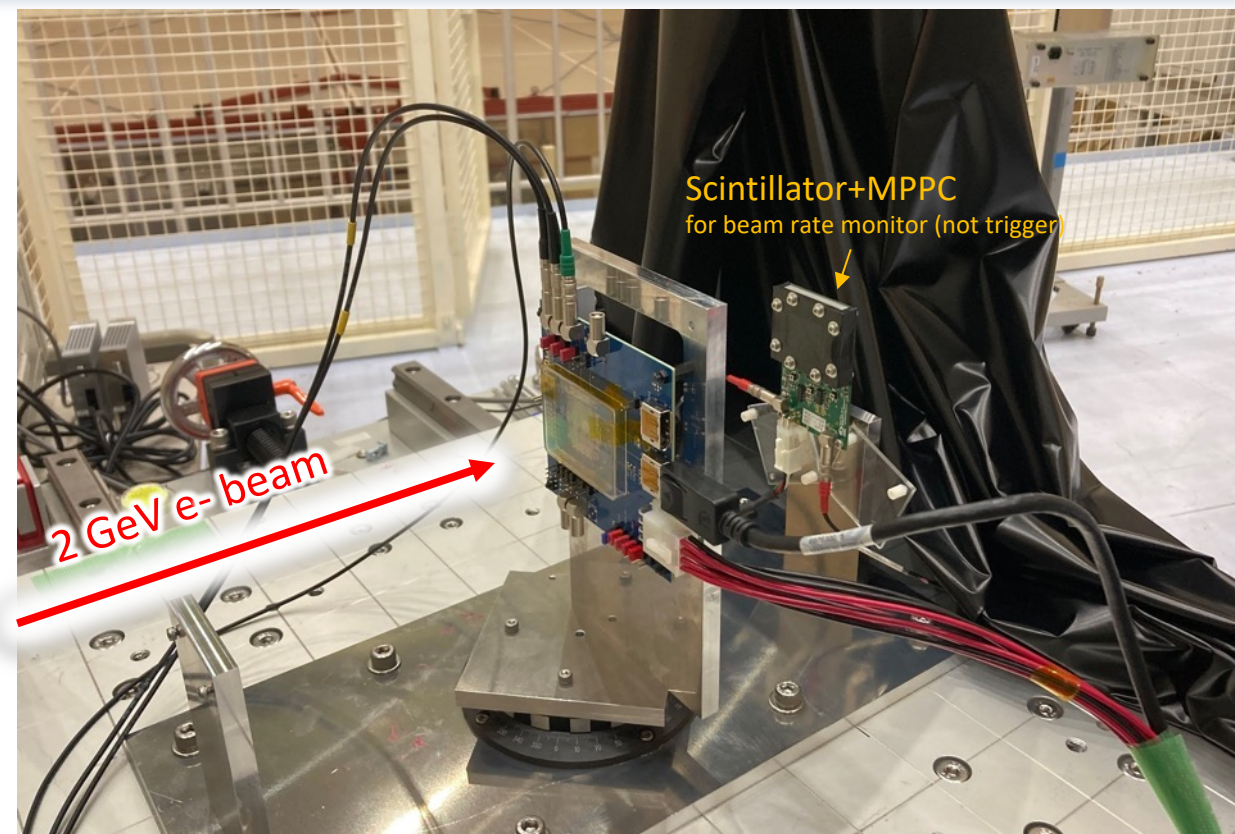
# KEK PF beam test (Mar 1-4, 2024)

## ■ 2 GeV e- beam

- Beam rate:
  - Counter in beamline:  $\sim 800\text{Hz}$
  - Downstream scintillator ( $32 \times 28\text{mm}^2$ ):  $\sim 50\text{Hz}$

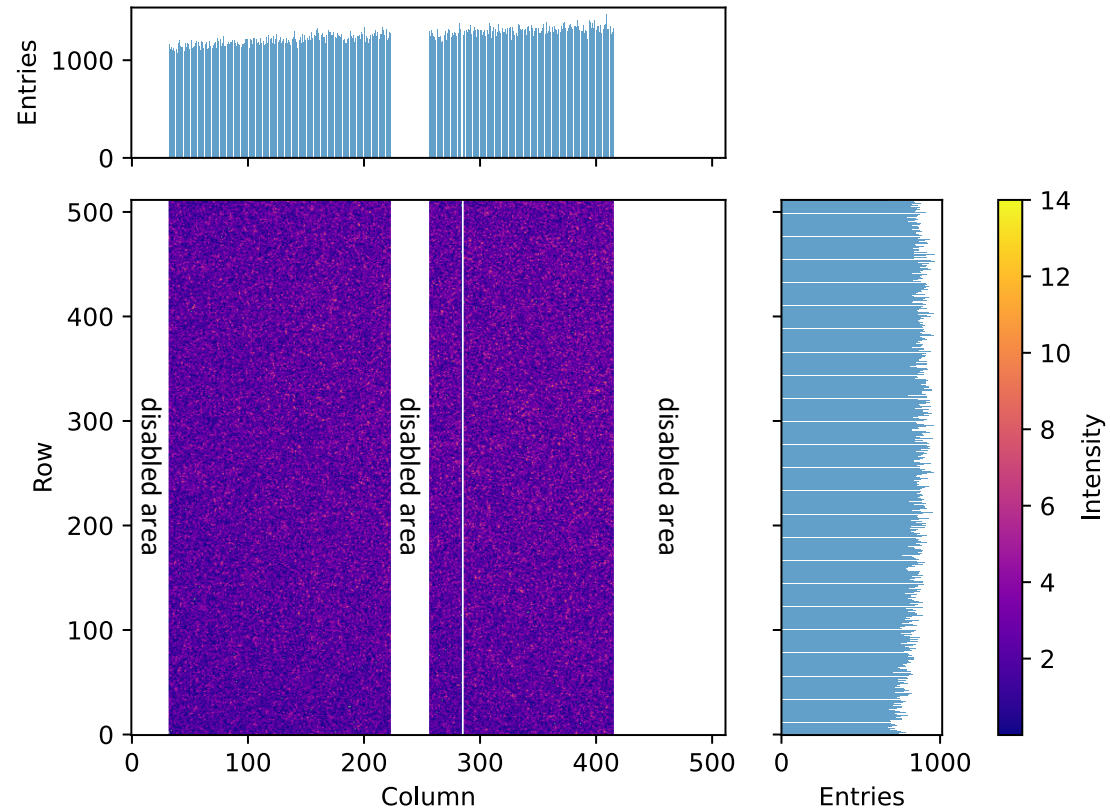
## ■ Tested single TJ-Monopix2 chip

- No telescope
- cluster size measurement with different incident angles
  - $\rightarrow$  evaluate depletion layer depth

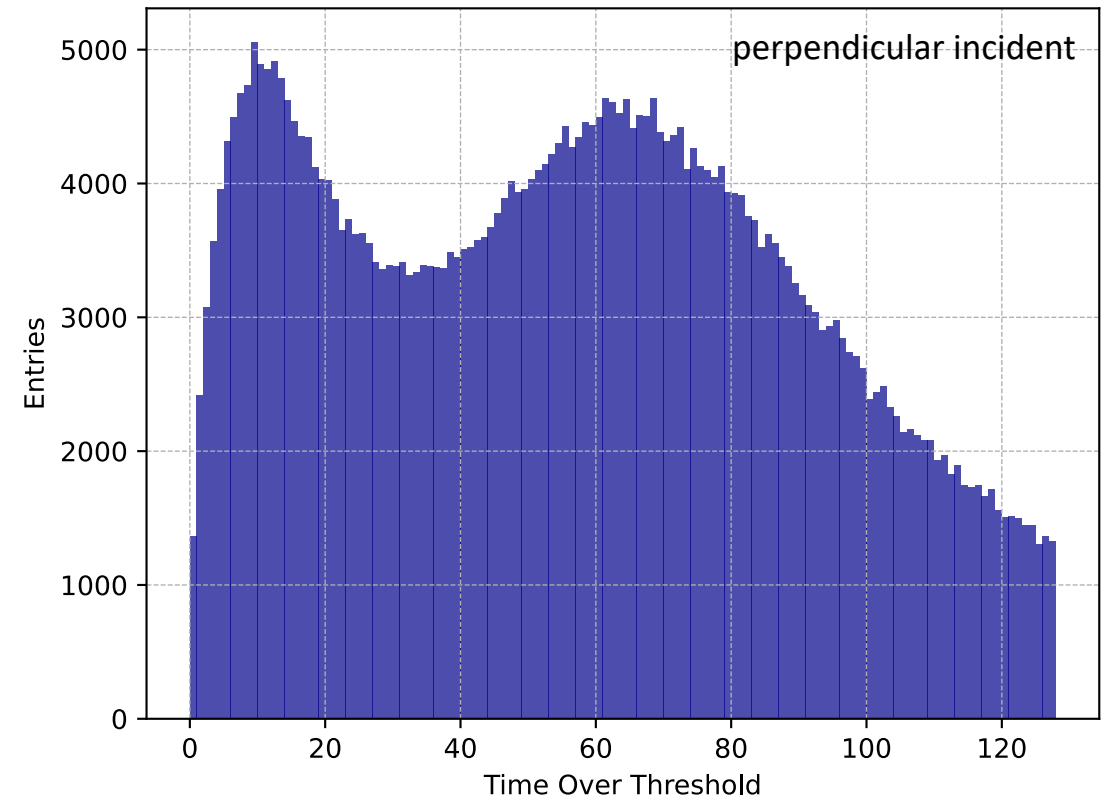


# Quick results from beam test

## Hit Map Distribution



## ToT Distribution





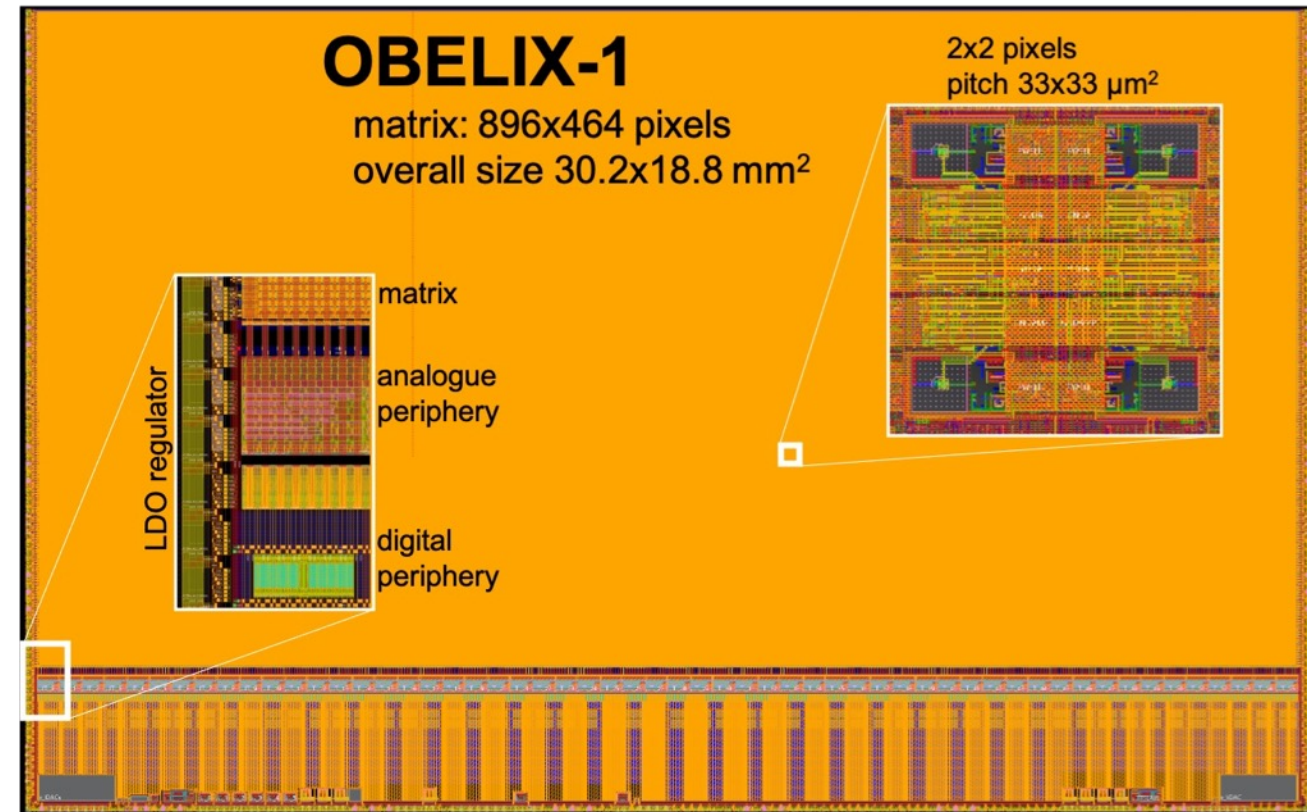
# DMAPS chip for Belle II vertex detector upgrade

## OBELIX chip

- Optimized BELle II monolithic pIXel sensor
- **Pixel matrix**
  - Extension from TJ-Monopix2
  - Clock frequency ~10-20 MHz
- **Power pads**
  - Power regulators added
- **Periphery**
  - Trigger-base readout

## 1st prototype: OBELIX-1

- **Design & production plan**
  - Designing main functionalities done (but regulator)
  - Final integration on-going
  - Simulation/verification is main activity
- **Submission: expected in late 2024**
  - after last in-person meeting



KEK ITDC E-sys (T. Kishishita) is contributing to designing matrix.

# Column-drain readout

